



103092.02

Group Art Unit: 2823

Examine

Docket No.:

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Nobuaki HASHIMOTO

Application No.: 09/991,931

Filed: November 26, 2001

SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING For:

THE SAME, CIRCUIT BOARD, AND ELECTRONIC INSTRUMENT

FAX RECEIVED

AMENDMENT UNDER 37 C.F.R. §1.111

FEB 1 9 2003

Director of the U.S. Patent and Trademark Office Washington, D.C. 20231

TECHNOLOGY CENTER 2800

Sir:

In reply to the December 13, 2002 Office Action, please amend the above-identified application as follows:

IN THE SPECIFICATION:

Page 25, lines 17-23, delete current paragraph and insert therefor:

In this way, after the penetrating holes 214a are formed, the conductive member 18 formed on the substrate 214, to constitute two-layer substrate. For example, if the substrate 214 is of a thermoplastic substance, it can be softened by heating, and a conductive foil adhered without the use of adhesive, and by etching thereof a conductive member 18 can be formed. Alternatively, sputtering may equally be applied.

IN THE CLAIMS:

Please replace claims 53, 70 and 71 as follows:

(Amended) A substrate having penetrating holes formed therein, the substrate 53. having a conductive member adhered on one side thereof by an adhesive material over a